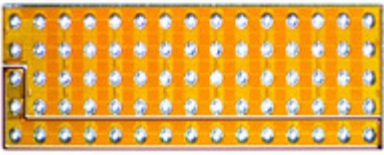
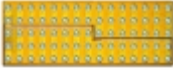


EFFICIENT POWER CONVERSION 	EPC2101ENG Manufacturer Part Number: EPC2101ENG Manufacturer/Brand: EPC Part of Description: TRANS GAN 2N-CH 60V BUMPED DIE Datasheets: PDF EPC2101ENG.pdf RoHs Status: RoHS Lead free / RoHS Stock Condition: Compliant New original, 2560 pcs Stock Available. Ship From: Hong Kong Shipment Way: DHL/Fedex/TNT/UPS/EMS
Image may be representation. See specs for product details.	

Specifications	
Part Number	EPC2101ENG
Manufacturer	EPC
Description	TRANS GAN 2N-CH 60V BUMPED DIE
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	2560 pcs Stock
Vgs(th) (Max) @ Id	2.5V @ 2mA
Supplier Device Package	Die
Series	eGaN®
Rds On (Max) @ Id, Vgs	11.5 mOhm @ 20A, 5V
Power - Max	-
Packaging	Tray
Package / Case	Die
Operating Temperature	-40°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	300pF @ 30V
Gate Charge (Qg) (Max) @ Vgs	2.7nC @ 5V
FET Type	2 N-Channel (Half Bridge)
FET Feature	GaNFET (Gallium Nitride)
Drain to Source Voltage (Vdss)	60V
Current - Continuous Drain (Id) @ 25°C	9.5A, 38A

--

You May Be Also Be interested

In:  EPC2103 EPC TRANS GAN SYMMETRICAL HALF BRIDG	 EPC2102ENG EPC TRANS GAN 2N-CH 60V BUMPED DIE	 EPC2101ENGRT EPC TRANS GAN ASYMMETRICAL HALF BRID	 EPC2100ENG EPC TRANS GAN 2N-CH 30V BUMPED DIE
 EPC2100 EPC TRANS GAN ASYMMETRICAL HALF BRID	 EPC2100ENGRT EPC MOSFET ARRAY 2N-CH 30V DIE	 EPC2101 EPC TRANS GAN ASYMMETRICAL HALF BRID	 EPC2102 EPC TRANS GAN SYMMETRICAL HALF BRIDG

EPC2101ENG Related keyword					More
EPC2101ENG EPC	EPC2101ENG Data Sheet	EPC2101ENG Datasheets	EPC2101ENG PDF	EPC EPC2101ENG	
EPC2101ENG Electronic	EPC2101ENG Components	EPC2101ENG Distributor	EPC2101ENG Image	EPC2101ENG Part	
EPC2101ENG Price	EPC2101ENG Manufacturer	EPC2101ENG Picture	EPC2101ENG Stock	EPC2101ENG Inventory	
EPC2101ENG New	EPC2101ENG Original	EPC2101ENG Warranted	EPC2101ENG RFQ	EPC2101ENG Order Online	